

DALLAS SEMICONDUCTOR IME

Goal = 300 ppm

Flow	Part	IME Results											
		1Q03			4Q02			3Q02			2Q02		
		Total	Fails	PPM	Total	Fails	PPM	Total	Fails	PPM	Total	Fails	PPM
D6E	DS4000							10083	5	496			
D6E	DS87C550	4374	11	2515									
D6H	DS1050												
D6H	DS21352												
D6H	DS21554							5878	21	3573			
D6H	DS2196												
D6L	DS7864B							4958	18	3630			
D6N	DS12885							10199	4	392			
D6N	DS1643												
D6RH	DS5240										3493	130	37217
D6RL	DS80C320							10082	14	1389			
D6RL	DS80CH11												
D6S	DS2118M	2836	0	0									
D6W	DS1848							10199	9	882			
D8ET	DS87C520												
D8G	DS1780												
D8N	DS17885	2533	45	17765							6799	173	25445
D8R-N	DS2154										8228	8	972
D8S	DS1232												
D8S	DS1834										7863	3	382
D8S	DS21T07												
D8W	DS1621										10200	8	784